MC3651 Series

1 cell lithium-ion/lithium-polymer battery protection IC

Outline

MC3651 series are protection IC with integrated MOS-FET for protection of the rechargeable Lithium-ion or Lithium-polymer battery. The overcharge, overdischarge and discharging and

charging overcurrent protection of the rechargeable one-cell Lithium-ion or Lithium-polymer battery can be detected.

Features	(Unl	ess otherwise specified, Ta=25°C)
1) Range and accuracy of detection/release vo	oltage	
	4.15V to 4.50V, 5mV step Ac	curacy±20mV
	•	curacy±25mV
		pr=-5°C to +60°C)
Overcharge release voltage	4.00V to 4.35V *1Ac	
	2.00V to 3.00V *2 Ac	
· · · · · · · · · · · · · · · · · · ·	2.00V to 3.00V *2 Ac	•
	20mV to 65mV, 1mV Ac	-
(Discharge current limit)		,
	–65mV to –25mV, 1mV Ac	curacy±5mV
(Charge current limit)		,
, ,	Selection from 0.19V, 0.36V Ac	curacy±50mV
2) Range of detection delay time		
Overcharge detection delay time	Selection from 1 0s fixed	
Overdischarge detection delay time		
	me Selection from 8ms, 12ms, 16ms, 20ms, 48	lms 224ms
,	e Selection from 8.5ms, 16.5ms, 32.5ms	7113, 22-1113
Short detection delay time		
Ghort detection delay time	Gelection from 6.55ms, 6.75ms	
3) 0V battery charge function	Selection from "Permission" or "Prohibition"	' *3
4) Low current consumption		
Normal mode	Τyp. 3.0μA, Max. 4.5μA	
Stand-by mode	Max. 0.1µA (In case Overdischarge latch ful	nction "Enable")
	Max. 0.5µA (In case Overdischarge latch fun	nction "Disable")
6) MOS-FET		
Source to Source on state resistance	Typ. 65.0mΩ (@VDD=3.5V)	
7) Absolute maximum ratings		
• VCC pin	0.3V to +12V	
• V- pin	VDD-24V to VDD+0.3V	
Drain-source voltage		
Drain current	Max. 1.2A	
Total Power Dissipation	Max. 0.4W	
Storage temperature		
Operation temperature	-40°C to ±85°C	

^{*1} Hysteresis voltagebetween Overcharge detection and release voltage is selectable from 0.10V/0.15V/0.20V/0.25V.
*2 Please inquire to us about details of the setting of Overdischarge detection and release voltage.
*3 In the case of "0V battery charge inhibition", the setting voltage is selectable from 0.65V/0.90V.
*4 Please inquire to us, if you need another specifications.

Pin assignment

■ PLP-4E

(Top view)	Pin no.	Symbol	Function
\$2 V-	1	S1	Negative power supply and source of discharge MOS-FET terminal. Connect to the negative terminal of the battery.
	2	VDD	Positive power supply voltage input terminal. Connect to the positive terminal of the battery through R1.
	3	V-	Charger negative voltage input terminal. Connect to S2 terminal through R2.
	4	S2	Source terminal of charge MOS-FET. Connect to a negative power supply terminal of charger.
S1 V ₀₀	-	D	Drain terminal of discharge and charge MOS-FET. Drain terminal must be open electrically.

LINE UP

	Optional function		Detection / Release voltage							Detection delay time				Optional function		MOS -FET			
Product name	Package	0V battery charge function	Overcharge detection Latch function	Overdischarge detection Latch function	Overcharge detection voltage	Overcharge release voltage	Overdischarge detection voltage	Overdischarge release voltage	Discharging overcurrent detection voltage (@VDD=3.5V)	Charging overcurrent detection voltage (@VDD=3.5V)	Short detection voltage	Overcharge detection delay time	Overdischarge detection delay time	Discharging overcurrent detection delay time	Charging overcurrent detection delay time	Short detection delay time	Discharge current limit (@VCC=3.5V)	Charge current limit (@VCC=3.5V)	Source to source on-state resistance (@VCC=3.5V)
			*1	*1	Vdet1	Vrel1	Vdet2	Vrel2	Vdet3	Vdet4	Vshort	tVdet1	tVdet2	tVdet3	tVdet4	tshort	Idischg	Icharge	Rss(on)
			ľ	'	٧	٧	٧	V	mV	mV	V	s	ms	ms	ms	μs	Α	Α	mΩ
MC3651DF1AAM	PLP-4E	0.65V	×	0	4.280	4.180	2.700	2.700	20.0	-25.0	0.190	1.0	100.0	20.0	8.5	750	0.315	0.390	65.0
MC3651DF3AAM	PLP-4E	0.90V	×	0	4.265	4.065	3.000	3.000	20.0	-25.0	0.190	1.0	100.0	20.0	8.5	500	0.315	0.390	65.0

^{*1} Optional functions

PLP-4E ... 5,000pcs/Reel

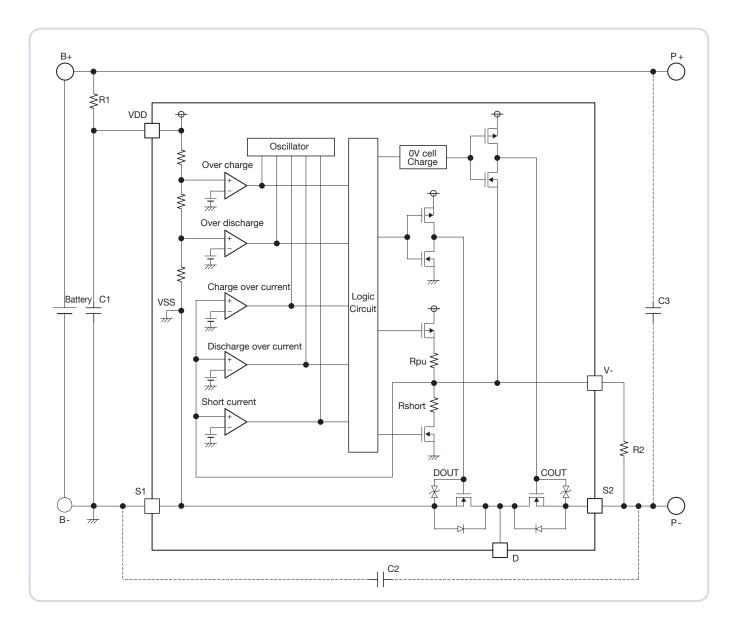
Please inquire to us, if you request a rank other than the above.

O Provided.

 $[\]times$ Not provided.

MC3651 Series

Typical application circuit



Symbol	Parts	Min.	Тур.	Max.	Purpose
R1	Resistor	-	330Ω	470Ω	For voltage fluctuation, For ESD
C1	Capacitor	-	0.1µF	-	For voltage fluctuation
R2	Resistor	-	2.7kΩ	-	Current limit for charger reverse connection
C2	Capacitor	-	0.1µF	-	For exogenous noise
C3	Capacitor	-	0.1µF	-	For exogenous noise